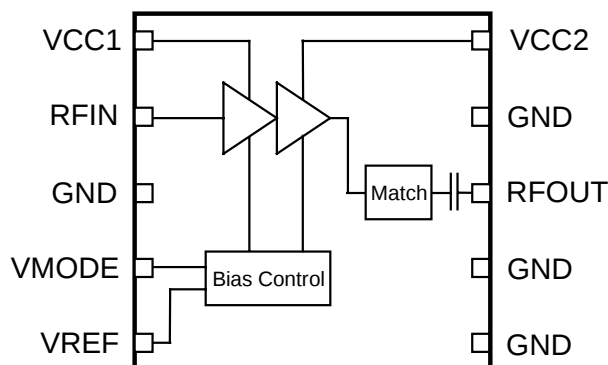


3V IMT2100 WCDMA Power Amplifier Module

Functional Block Diagram



Product Description

Advanced compact 3V linear power amplifier module designed for mobile UMTS handset applications in IMT2100 band. The small size and high performance is achieved with high-reliability InGaP HBT technology. The module is fully integrated, providing a simple 50 Ohms interface on input and output ports. No external matching or bias components are required. Despite its very compact size, the module has exceptional efficiency and linearity. The module provides high/low output power modes and supports low power mode operation at reduced supply voltage.

Electrical Specifications

IMT2100 band				
Parameter	Min.	Typ.	Max.	Unit
Frequency	1920		1980	MHz
Pout high mode ¹	27.5			dBm
PAE high mode ¹		40		%
Pout low mode ²	16			dBm
PAE low mode ²		20		%
ACPR 5MHz ^{1,2}		-40		dBc
ACPR 10MHz ^{1,2}		-50		dBc

Note 1: Test Conditions CDMA High Mode: $V_{CC1}=3.4VDC$, $V_{CC2}=3.4VDC$, $V_{REF}=2.85VDC$, $V_{MODE}=LOW$, $T_c=25^{\circ}C$, $Z_S=Z_L=50\text{ Ohm}$, $P_{out} = 27.5dBm$

Note 2: Test Conditions CDMA Low Mode: $V_{CC1}=3.4VDC$, $V_{CC2}=1.2VDC$, $V_{REF}=2.85VDC$, $V_{MODE}=HIGH$, $T_c=25^{\circ}C$, $Z_S=Z_L=50\text{ Ohm}$, $P_{out} = 16dBm$

Features

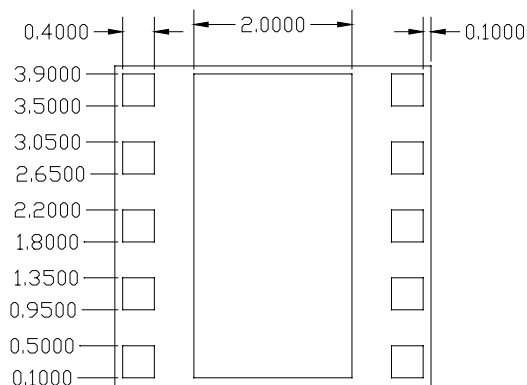
- Very compact size – 4 x 4 x 1.1mm³
- For 3G UMTS designs in IMT2100 band
- High/low output power modes
- High efficiency – high mode 40% typical
- Supports low collector voltage operation
- Low Vref of 2.85V nominal
- 10 pin package
- Positive supply voltage – 3.2 to 4.2 V
- 50 Ω input and output impedances
- High-reliability InGaP technology

Applications

- For 3G WCDMA designs in IMT2100 band

Package Style

4mm x 4mm LGA package (dimensions in mm):



3V IMT2100 WCDMA Power Amplifier Module

Absolute Maximum Ratings

Item #	Parameter	Symbol	Specification			Unit	Remarks
			Min.	Typ.	Max.		
1	DC Supply Voltage 1	V_{CC1}	-0.5		4.5	V	
2	DC Supply Voltage 2	V_{CC2}	-0.5		4.5	V	
3	Reference Voltage	V_{REF}	-0.5		3.5	V	
4	Mode Control Voltage	V_{MODE}	-0.5		3.5	V	
5	RF Input Power	P_{IN}			10	dBm	
6	Storage Temperature	T_S	-55		155	°C	

Note: The part may not survive all maximums applied simultaneously.

Operating Conditions

Item #	Parameter	Symbol	Specification			Unit	Remarks
			Min.	Typ.	Max.		
1	DC Supply Voltage 1	V_{CC1}	3.2	3.4	4.2	V	
2	DC Supply Voltage 2						
	High Power Mode	V_{CC2}	3.2	3.4	4.2	V	
	Low Power Mode	V_{CC2}	1.2		4.2	V	
3	Reference Voltage						
	PA on	V_{REF}	2.75	2.85	2.95	V	
	PA off	V_{REF}	0		0.5	V	
4	Mode Control Voltage						
	High Power Mode	V_{MODE}	0		0.5	V	
	Low Power Mode	V_{MODE}	2.5		3.0	V	
5	Operating Case Temperature	T_C	-30	25	85	°C	

DC Operating Parameters ^{1,2}

Item #	Parameter	Symbol	Specification			Unit	Remarks
			Min.	Typ.	Max.		
1	Idle Current						
	High Power Mode	$I_{Q,H}$		80		mA	
	Low Power Mode	$I_{Q,L}$		30		mA	
2	Reference Current	I_{REF}		3		mA	
3	Mode Control Current	I_{MODE}		100		μA	
4	Leakage Current	$I_{BATT,OFF}$			10	μA	$V_{CC1/2}$ =High, V_{MODE} =Low, V_{REF} =Low

Advance Data Sheet: Subject to change without notice

For additional information and latest specifications, see our website: www.triquint.com

Revision B, January 20, 2005

3V IMT2100 WCDMA Power Amplifier Module

WCDMA Electrical Characteristics in IMT2100 Band ^{1,2}

Item #	Parameter	Symbol	Specification			Unit	Remarks
			Min.	Typ.	Max.		
1	Operating Frequency	f	1920		1980	MHz	
2	Output Power						
	High Power Mode	P _{OUT,H}	27.5			dBm	
	Low Power Mode	P _{OUT,L}	16			dBm	
3	Gain						
	High Power Mode	G _H		27		dB	
	Low Power Mode (V _{CC2} =V _{BAT})	G _L		24		dB	
	Low Power Mode (V _{CC2} =1.2V)	G _L		23		dB	
4	Power Added Efficiency	PAE					
	High Power Mode			40		%	V _{CC2} =3.4V; P _{OUT} =27.5dBm
	Low Power Mode (V _{CC2} =V _{BAT})			10		%	V _{CC2} =3.4V; P _{OUT} =16dBm
	Low Power Mode (V _{CC2} =1.2V)			20		%	V _{CC2} =1.2V; P _{OUT} =16dBm
5	Adjacent Channel Power Ratio						measured in a 3.84 MHz bandwidth
	±5MHz	ACPR1		-40		dBc	
	±10MHz	ACPR2		-50		dBc	
6	Harmonics						P _{OUT} ≤ 27.5dBm
		H2		-60		dBc	
		H3		-70		dBc	
7	Input Match			1.5:1		VSWR	Z _{IN} = 50Ohm
8	Noise Power in Rx band	N _{RX}		-140		dBm/Hz	2110-2170 MHz
9	Load Mismatch Stability All Spurious < -70dBc		5:1			VSWR	all angles
10	Load Mismatch Ruggedness No Damage		10:1			VSWR	all angles, P _{IN} ≤ +5dBm

Note 1: Test Conditions unless otherwise specified: V_{CC1}=3.4VDC, V_{CC2}=3.4VDC, V_{REF}=2.85VDC, Z_S=Z_L=50 Ohm, T_C = 25 °C.

Note 2: TriQuint Test Board

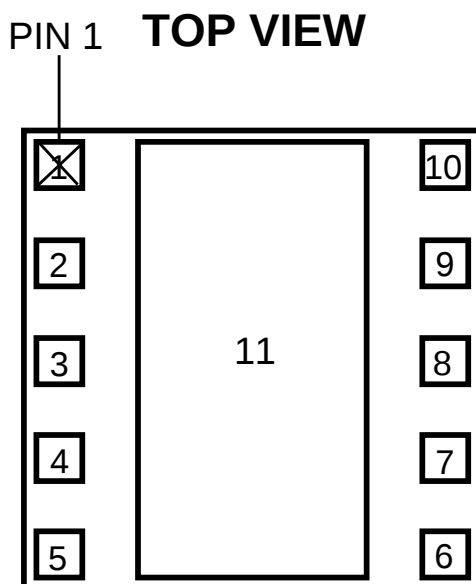
Advance Data Sheet: Subject to change without notice

For additional information and latest specifications, see our website: www.triquint.com

Revision B, January 20, 2005

3V IMT2100 WCDMA Power Amplifier Module

Pin Out and Assignments

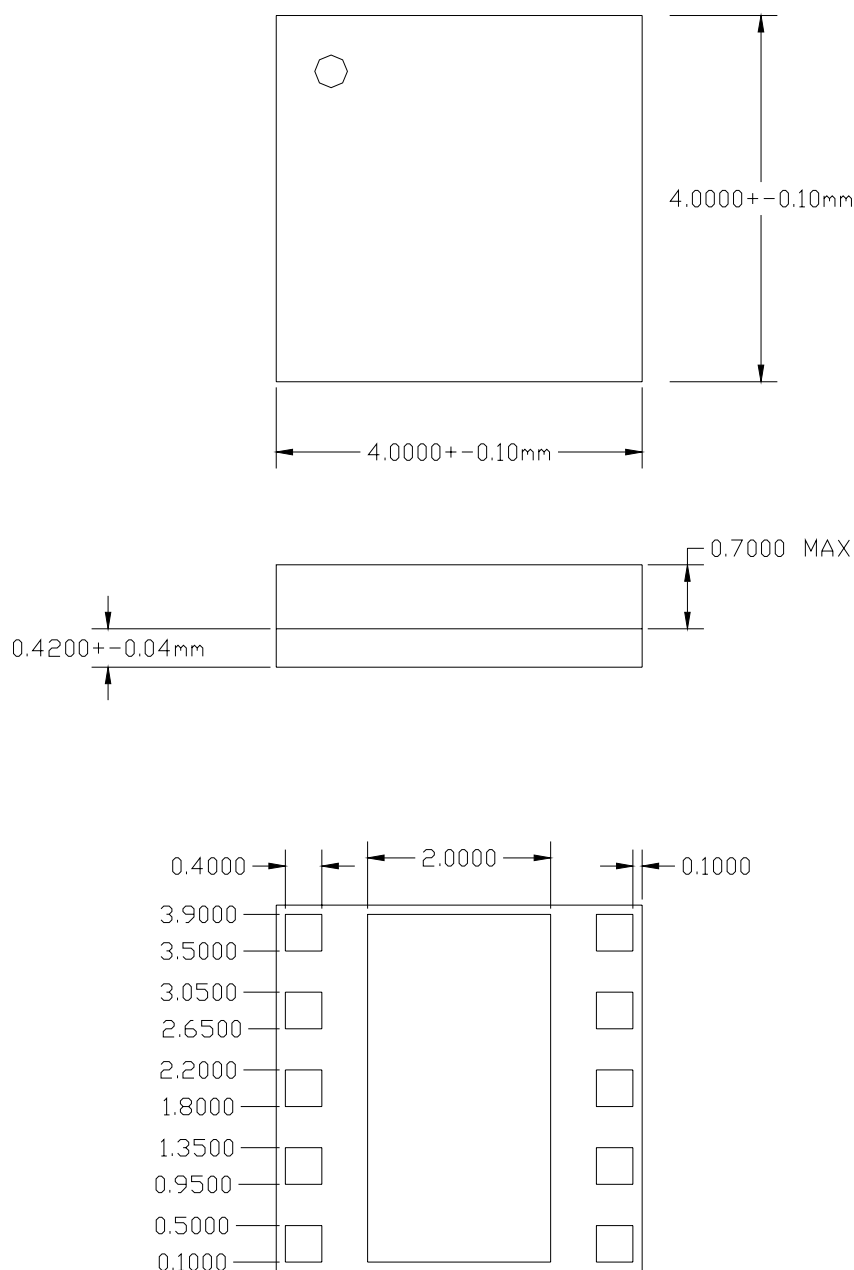


Pin #	Description	Function
1	V _{CC1}	Supply Voltage V _{CC1}
2	RF _{IN}	RF input (DC path to Ground, RF impedance 50 Ohms)
3	GND	Ground
4	V _{MODE}	Digital Control Signal for Output Power Mode Setting
5	V _{REF}	Reference Voltage, typ. 2.85V, $\pm 100\text{mV}$
6	GND	Ground
7	GND	Ground
8	RF _{OUT}	RF output (DC decoupled, RF impedance 50 Ohms)
9	GND	Ground
10	V _{CC2}	Supply Voltage V _{CC2}
11	GND	Ground

3V IMT2100 WCDMA Power Amplifier Module

Packaging and Tape & Reel Information

all dimensions in mm:



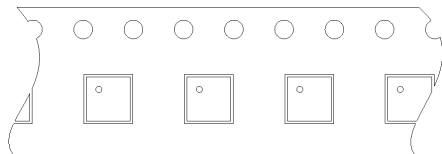
Advance Data Sheet: Subject to change without notice

For additional information and latest specifications, see our website: www.triquint.com

Revision B, January 20, 2005

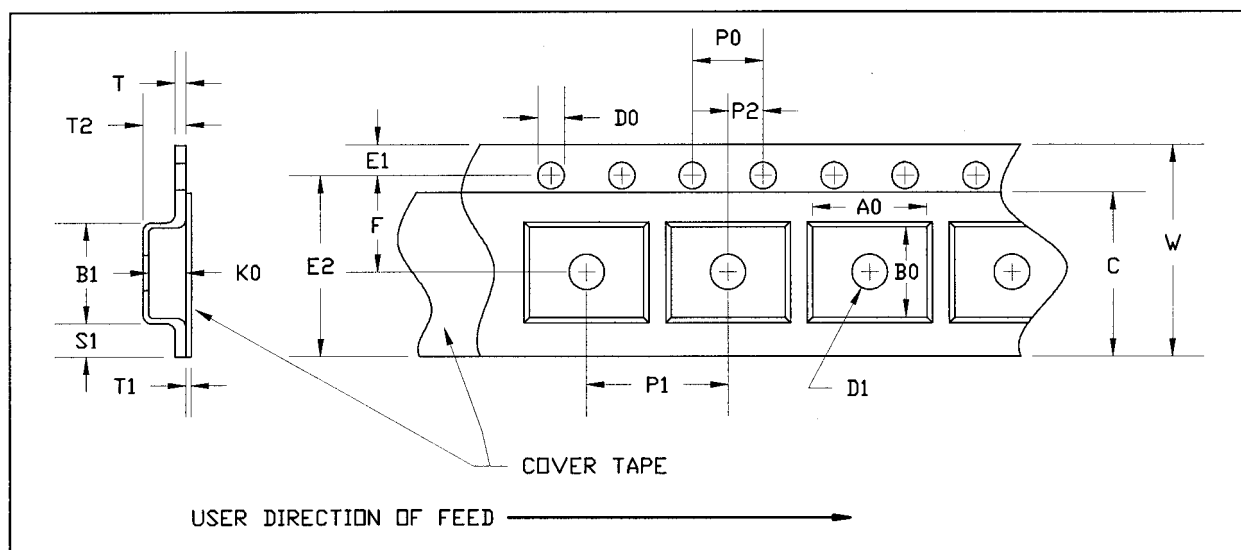
3V IMT2100 WCDMA Power Amplifier Module

Module Orientation:



→ user direction of feed

Carrier and Cover Tape Physical Dimensions:



PART	FEATURE	SYMBOL	SIZE (in)	SIZE (mm)
CAVITY	LENGTH	A0	0.171	4.35
	WIDTH	B0	0.171	4.35
	DEPTH	K0	0.071	1.80
	PITCH	P1	0.315	8.00
DISTANCE BETWEEN CENTERLINE	CAVITY TO PERFORATION LENGTH DIRECTION	P2	0.079	2.00
	CAVITY TO PERFORATION WIDTH DIRECTION	F	0.217	5.50
COVER TAPE	WIDTH	C	0.362	9.20
CARRIER TAPE	WIDTH	W	0.472	12.00

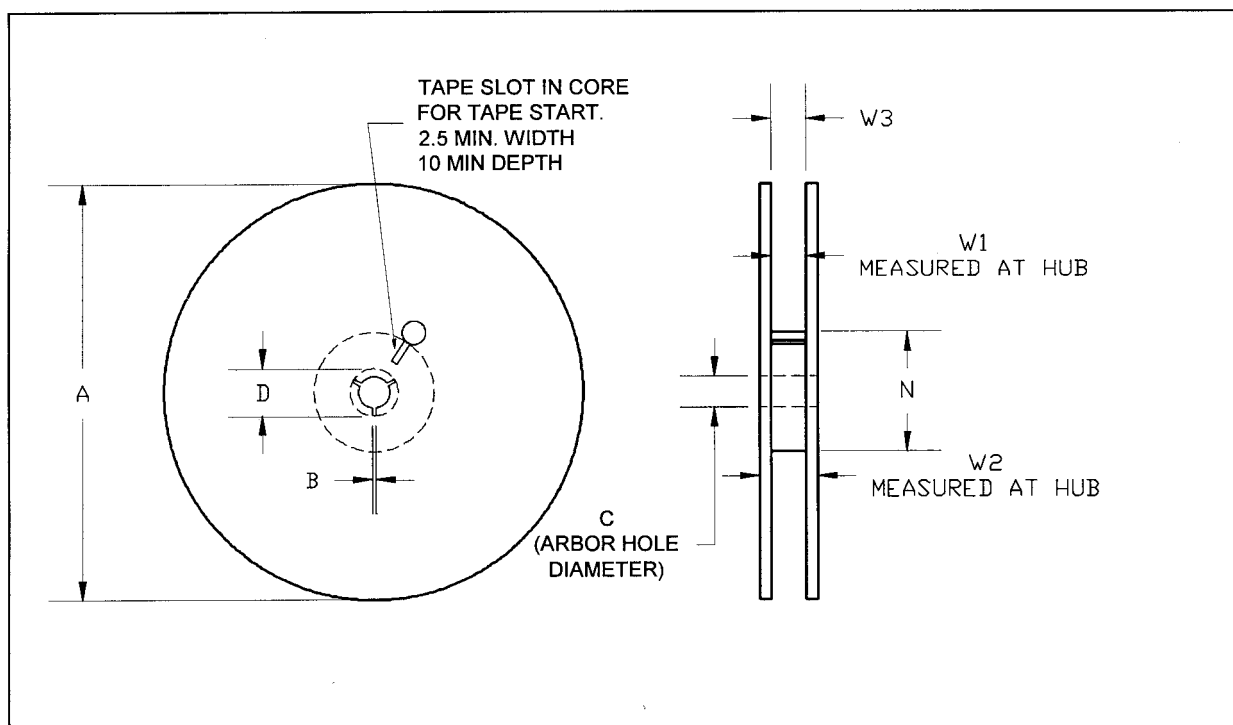
Advance Data Sheet: Subject to change without notice

For additional information and latest specifications, see our website: www.triquint.com

Revision B, January 20, 2005

3V IMT2100 WCDMA Power Amplifier Module

Reel Physical Dimensions:



TQM7M6001			13" REEL	
PART	FEATURE	SYMBOL	SIZE (in)	SIZE (mm)
FLANGE	DIAMETER	A	12.992	330
	THICKNESS	W2	0.717	18.2
	SPACE BETWEEN FLANGE	W1	0.504	12.8
HUB	OUTER DIAMETER	N	4.016	102.0
	ARBOR HOLE DIAMETER	C	0.512	13.0
	KEY SLIT WIDTH	B	0.079	2.0
	KEY SLIT DIAMETER	D	0.787	20.0

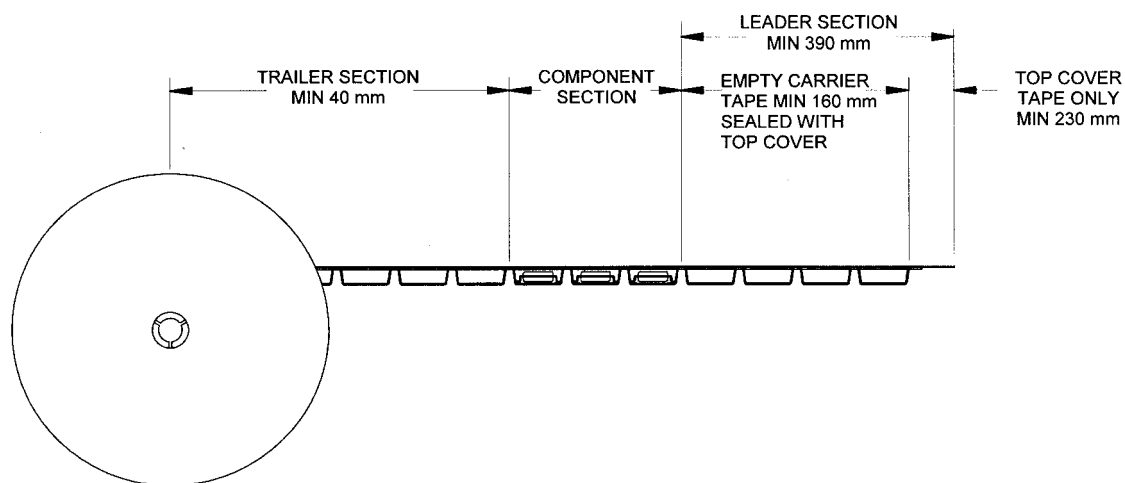
Advance Data Sheet: Subject to change without notice

For additional information and latest specifications, see our website: www.triquint.com

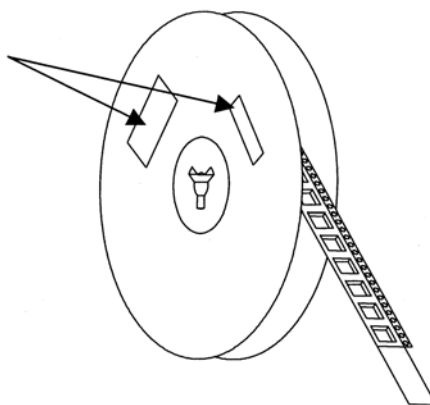
Revision B, January 20, 2005

3V IMT2100 WCDMA Power Amplifier Module

Completed Tape and Reel Assembly:



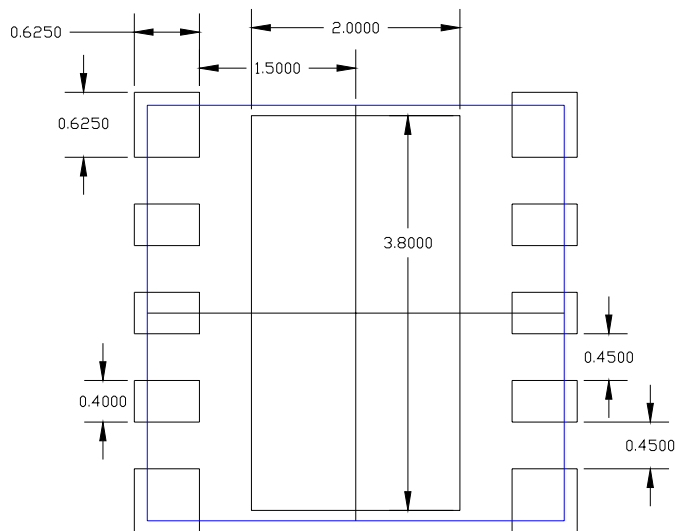
Product label, Mfg Label and ESD label are placed on the flange opposite to the sprockets in the carrier tape



3V IMT2100 WCDMA Power Amplifier Module

PC Board Layout recommendations

all dimensions in mm:



Additional Information ¹T

1 For latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

Web: www.triquint.com

Tel: (+1)(503) 615-9000

Email: info_wireless@tqs.com

Fax: (+1)(503) 615-8902

For technical questions and additional information on specific applications:

Email: info_wireless@tqs.com

The information provided herein is believed to be reliable; TriQuint assumes no liability for inaccuracies or omissions. TriQuint assumes no responsibility for the use of this information, and all such information shall be entirely at the user's own risk. Prices and specifications are subject to change without notice. No patent rights or licenses to any of the circuits described herein are implied or granted to any third party.

TriQuint does not authorize or warrant any TriQuint product for use in life-support devices and/or systems.

Copyright © 2005 TriQuint Semiconductor, Inc. All rights reserved.

Advance Data Sheet: Subject to change without notice

For additional information and latest specifications, see our website: www.triquint.com

Revision B, January 20, 2005